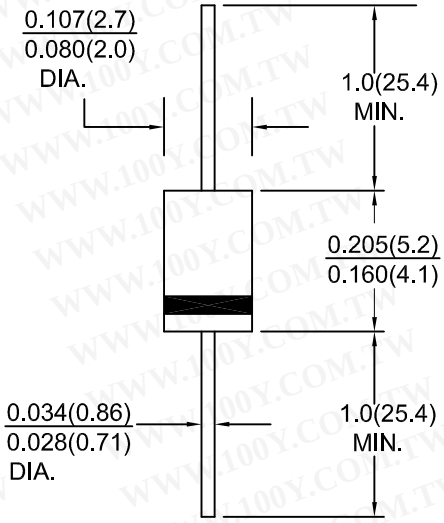
FR101G THRU FR107G

FAST RECOVERY GLASS PASSIVATED RECTIFIERS

FEATURES:

- High temperature bonded construction
- Fast switching for use in high frequency circuit
- No thermal runaway at 1 Amp. Current Ta=55℃
- High temperature soldering guaranteed : 250 ℃/10 seconds, 0.375" lead length, 5lbs.(2.3kg) tension

DO-204AL(DO-41)



Dimensions in inches and (millimeters)

MECHANICAL DATA

Case : Molded plastic use UL 94V-0 recognized flame retardant epoxy
Terminals : Axial leads, solderable per MIL-STD-202, Method 208
Polarity : Color band on body denotes cathode end
Mounting Position : Any
Weight : 0.33 grams, 0.012 ounce

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25℃ ambient temp. unless otherwise specified.
Single phase, half sine wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20 %.

Characteristic	Symbol	FR 101G	FR 102G	FR 103G	FR 104G	FR 105G	FR 106G	FR 107G	Units
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	Volts
Maximum average forward rectified current .375 lead length at Ta=55℃	I_O	1.0							Amps
Peak forward surge current ,8.3ms single half sine-wave superimposed on rated load(JEDEC Method)	I_{FSM}	30.0							Amps
Maximum instantaneous forward voltage drop at 1.0 A	V_F	1.3							Volts
Maximum DC reverse current Ta=25℃ at rated DC blocking voltage Ta=150℃	I_R	5.0 200.0							μA
Typical reverse recovery time (note 1)	trr	150	150	150	150	250	250	500	nS
Typical thermal resistance	R_{th-JA}	55							℃/W
Typical junction capacitance (note 2)	C_j	15.0							pF
Operating junction and storage temperature range	T_j, T_{stg}	-65 to +150							℃

NOTES:1. Reverse recovery test condition; I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
2. Measured at 1MHz and Applied reverse voltage of 4.0V.DC

DACO SEMICONDUCTOR

RATINGS AND CHARACTERISTIC CURVES FR101G THRU FR107G

FIG.1-DERATING CURVE FOR OUTPUT RECTIFIER CURRENT

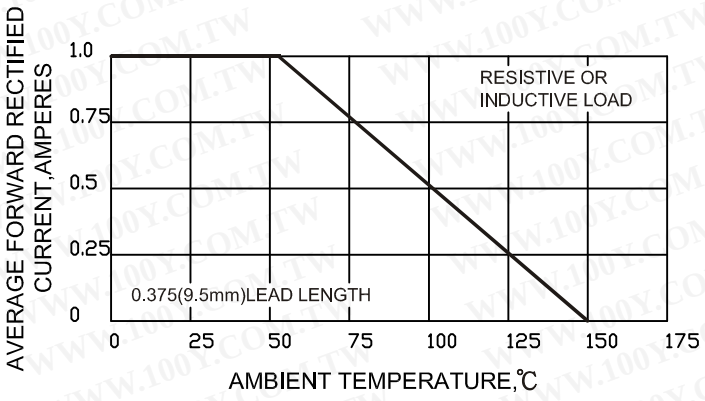


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

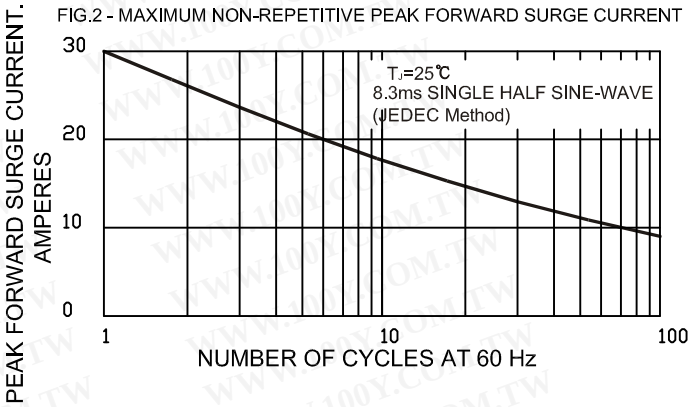


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

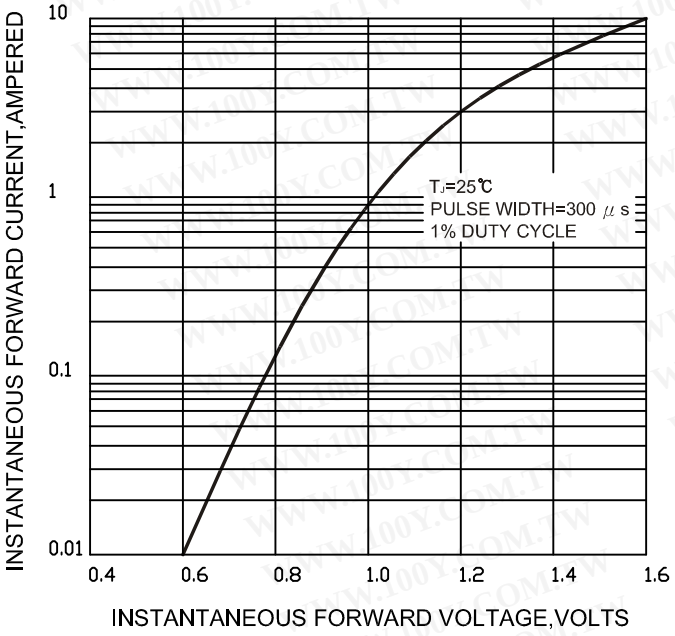


FIG.4-TYPICAL REVERSE CHARACTERISTICS

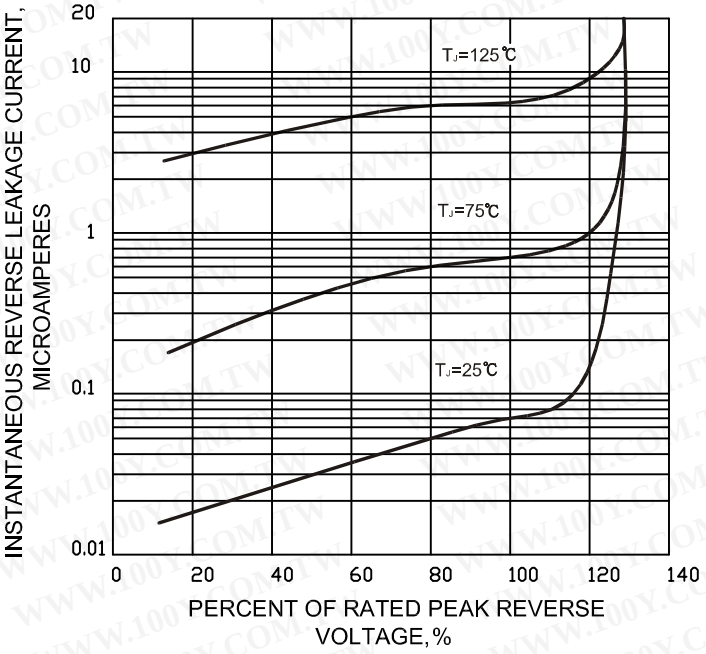
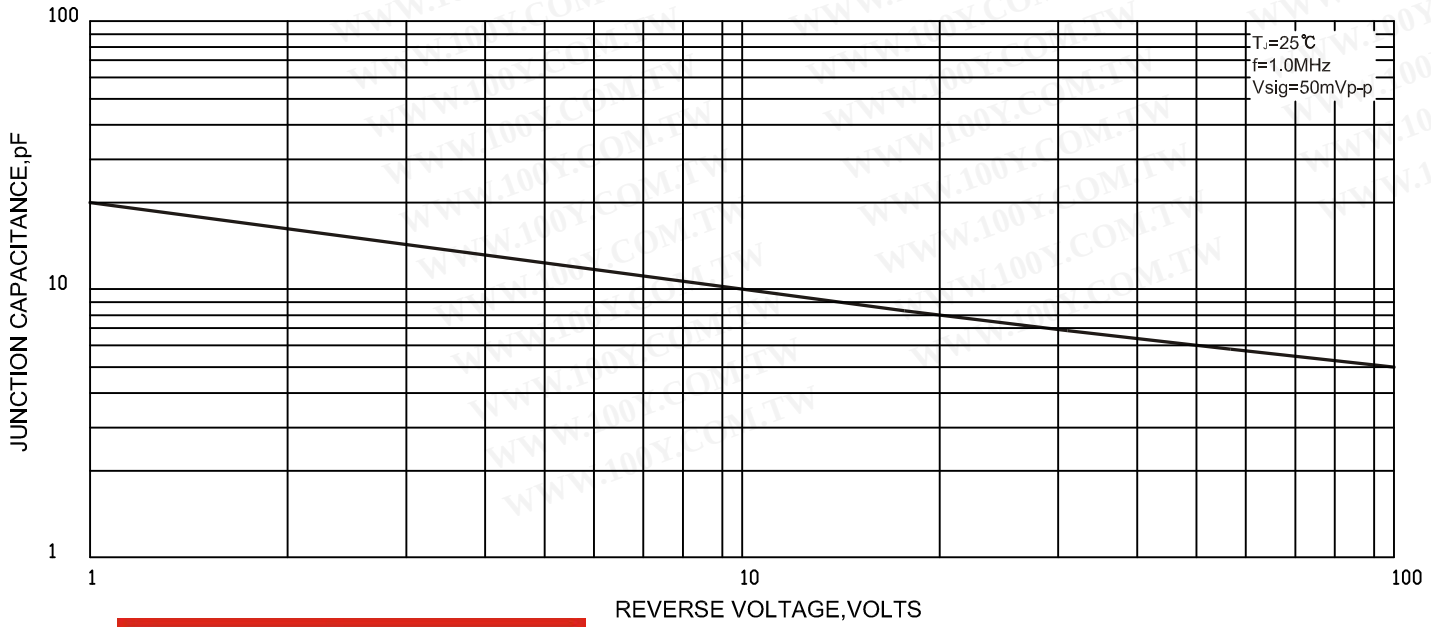


FIG.5-TYPICAL JUNCTION CAPACITANCE



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